

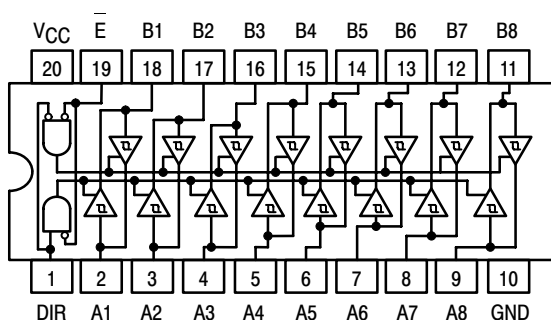
# SN74LS245

## Octal Bus Transceiver

The SN74LS245 is an Octal Bus Transmitter/Receiver designed for 8-line asynchronous 2-way data communication between data buses. Direction Input (DR) controls transmission of Data from bus A to bus B or bus B to bus A depending upon its logic level. The Enable input (E) can be used to isolate the buses.

- Hysteresis Inputs to Improve Noise Immunity
- 2-Way Asynchronous Data Bus Communication
- Input Diodes Limit High-Speed Termination Effects
- ESD > 3500 Volts

### LOGIC AND CONNECTION DIAGRAMS DIP (TOP VIEW)



### TRUTH TABLE

INPUTS		OUTPUT
E	DIR	
L	L	Bus B Data to Bus A
L	H	Bus A Data to Bus B
H	X	Isolation

H = HIGH Voltage Level  
L = LOW Voltage Level  
X = Immaterial

### GUARANTEED OPERATING RANGES

Symbol	Parameter	Min	Typ	Max	Unit
V <sub>CC</sub>	Supply Voltage	4.75	5.0	5.25	V
T <sub>A</sub>	Operating Ambient Temperature Range	0	25	70	°C
I <sub>OH</sub>	Output Current – High			–3.0	mA
				–15	mA
I <sub>OL</sub>	Output Current – Low			24	mA

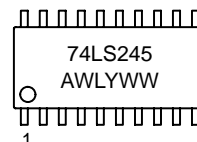
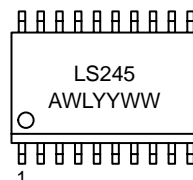
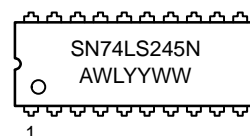
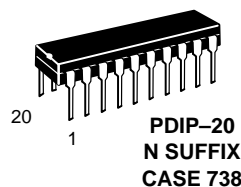


ON Semiconductor

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**LOW  
POWER  
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### MARKING DIAGRAMS



A = Assembly Location  
WL = Wafer Lot  
YY = Year  
WW = Work Week

### ORDERING INFORMATION

Device	Package	Shipping
SN74LS245N	PDIP-20	1440 Units/Box
SN74LS245DW	SOIC-WIDE	38 Units/Rail
SN74LS245DWR2	SOIC-WIDE	2500/Tape & Reel
SN74LS245M	SOEIAJ-20	See Note 1.
SN74LS245MEL	SOEIAJ-20	See Note 1.

1. For ordering information on the EIAJ version of the SOIC package, please contact your local ON Semiconductor representative.

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## DC CHARACTERISTICS OVER OPERATING TEMPERATURE RANGE (unless otherwise specified)

Symbol	Parameter	Limits			Unit	Test Conditions
		Min	Typ	Max		
V <sub>IH</sub>	Input HIGH Voltage	2.0			V	Guaranteed Input HIGH Voltage for All Inputs
V <sub>IL</sub>	Input LOW Voltage			0.8	V	Guaranteed Input LOW Voltage for All Inputs
V <sub>T+</sub> –V <sub>T–</sub>	Hysteresis	0.2	0.4		V	V <sub>CC</sub> = MIN
V <sub>IK</sub>	Input Clamp Diode Voltage		–0.65	–1.5	V	V <sub>CC</sub> = MIN, I <sub>IN</sub> = –18 mA
V <sub>OH</sub>	Output HIGH Voltage	2.4	3.4		V	V <sub>CC</sub> = MIN, I <sub>OH</sub> = –3.0 mA
		2.0			V	V <sub>CC</sub> = MIN, I <sub>OH</sub> = MAX
V <sub>OL</sub>	Output LOW Voltage		0.25	0.4	V	I <sub>OL</sub> = 12 mA, V <sub>CC</sub> = V <sub>CC</sub> MIN, V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub> per Truth Table
			0.35	0.5	V	I <sub>OL</sub> = 24 mA
I <sub>OZH</sub>	Output Off Current HIGH			20	μA	V <sub>CC</sub> = MAX, V <sub>OUT</sub> = 2.7 V
I <sub>OZL</sub>	Output Off Current LOW			–200	μA	V <sub>CC</sub> = MAX, V <sub>OUT</sub> = 0.4 V
I <sub>IH</sub>	Input HIGH Current	A or B, DR or E		20	μA	V <sub>CC</sub> = MAX, V <sub>IN</sub> = 2.7 V
		DR or E		0.1	mA	V <sub>CC</sub> = MAX, V <sub>IN</sub> = 7.0 V
		A or B		0.1	mA	V <sub>CC</sub> = MAX, V <sub>IN</sub> = 5.5 V
I <sub>IL</sub>	Input LOW Current			–0.2	mA	V <sub>CC</sub> = MAX, V <sub>IN</sub> = 0.4 V
I <sub>OS</sub>	Output Short Circuit Current (Note 2.)	–40		–225	mA	V <sub>CC</sub> = MAX
I <sub>CC</sub>	Power Supply Current Total, Output HIGH			70	mA	V <sub>CC</sub> = MAX
	Total, Output LOW			90		
	Total at HIGH Z			95		

2. Not more than one output should be shorted at a time, nor for more than 1 second.

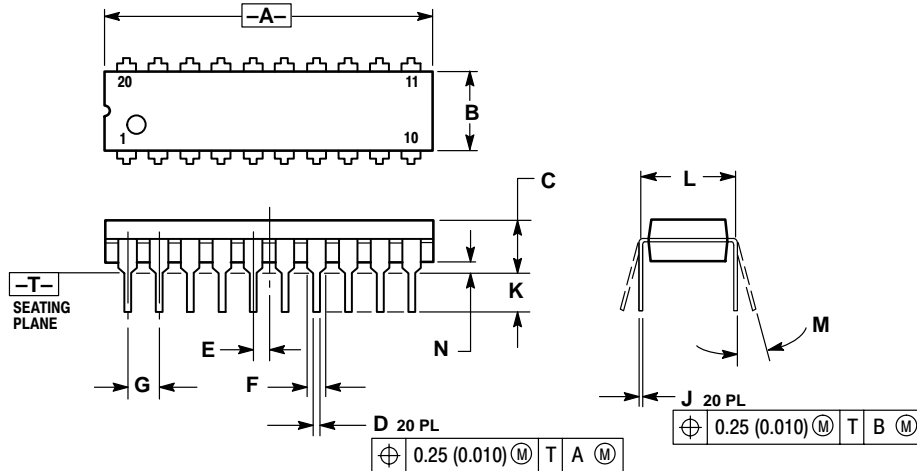
## AC CHARACTERISTICS (T<sub>A</sub> = 25°C, V<sub>CC</sub> = 5.0 V, T<sub>RISE</sub>/T<sub>FALL</sub> ≤ 6.0 ns)

Symbol	Parameter	Limits			Unit	Test Conditions
		Min	Typ	Max		
t <sub>PLH</sub> t <sub>PHL</sub>	Propagation Delay, Data to Output		8.0 8.0	12 12	ns	C <sub>L</sub> = 45 pF, R <sub>L</sub> = 667 Ω
t <sub>PZH</sub>	Output Enable Time to HIGH Level		25	40	ns	
t <sub>PZL</sub>	Output Enable Time to LOW Level		27	40	ns	
t <sub>PLZ</sub>	Output Disable Time from LOW Level		15	25	ns	C <sub>L</sub> = 5.0 pF, R <sub>L</sub> = 667 Ω
t <sub>PHZ</sub>	Output Disable Time from HIGH Level		15	25	ns	

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## PACKAGE DIMENSIONS

### N SUFFIX PLASTIC PACKAGE CASE 738-03 ISSUE E

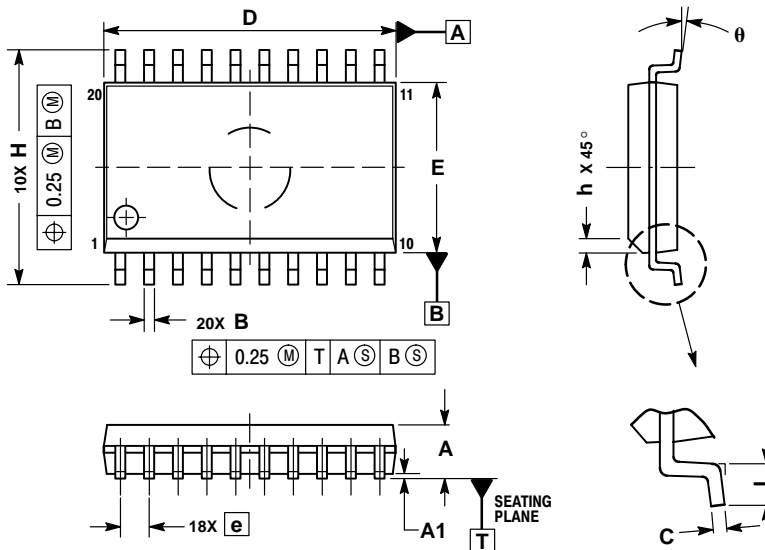


#### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	1.010	1.070	25.66	27.17
B	0.240	0.260	6.10	6.60
C	0.150	0.180	3.81	4.57
D	0.015	0.022	0.39	0.55
E	0.050 BSC		1.27 BSC	
F	0.050	0.070	1.27	1.77
G	0.100 BSC		2.54 BSC	
J	0.008	0.015	0.21	0.38
K	0.110	0.140	2.80	3.55
L	0.300 BSC		7.62 BSC	
M	0°	15°	0°	15°
N	0.020	0.040	0.51	1.01

### D SUFFIX PLASTIC SOIC PACKAGE CASE 751D-05 ISSUE F



#### NOTES:

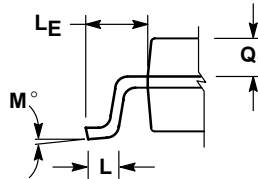
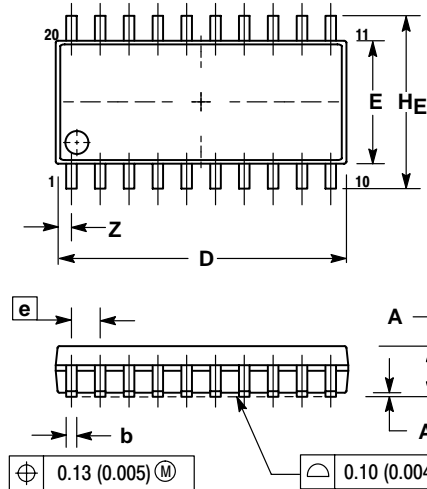
1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

DIM	MILLIMETERS	
	MIN	MAX
A	2.35	2.65
A1	0.10	0.25
B	0.35	0.49
C	0.23	0.32
D	12.65	12.95
E	7.40	7.60
e	1.27 BSC	
H	10.05	10.55
h	0.25	0.75
L	0.50	0.90
θ	0°	7°

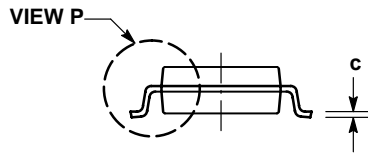
# SN74LS245

## PACKAGE DIMENSIONS

**M SUFFIX**  
SOEIAJ PACKAGE  
CASE 967-01  
ISSUE O




DETAIL P



### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH OR PROTRUSIONS AND ARE MEASURED AT THE PARTING LINE. MOLD FLASH OR PROTRUSIONS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
5. THE LEAD WIDTH DIMENSION (b) DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE LEAD WIDTH DIMENSION AT MAXIMUM MATERIAL CONDITION. DAMBAR CANNOT BE LOCATED ON THE LOWER RADIUS OR THE FOOT. MINIMUM SPACE BETWEEN PROTRUSIONS AND ADJACENT LEAD TO BE 0.46 (0.018).

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	---	2.05	---	0.081
A <sub>1</sub>	0.05	0.20	0.002	0.008
b	0.35	0.50	0.014	0.020
c	0.18	0.27	0.007	0.011
D	12.35	12.80	0.486	0.504
E	5.10	5.45	0.201	0.215
e	1.27 BSC		0.050 BSC	
HE	7.40	8.20	0.291	0.323
L	0.50	0.85	0.020	0.033
LE	1.10	1.50	0.043	0.059
M	0°	10°	0°	10°
Q <sub>1</sub>	0.70	0.90	0.028	0.035
Z	---	0.81	---	0.032

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